

TR BD243C;FSC;TO220;tranzystor; NPN;6A;115V;65W;>3MHz;RoHS



Dane techniczne:

Nazwa: BD243C

Typ tranzystora: bipolarny Kierunek przewodnictwa: NPN

Prąd kolektora: 6A

Napięcie kolektor-emiter: 115V

Moc: 65W

Częstotliwość: >3MHz

Obudowa: TO220

Montaż: przewlekany (THT)

Producent: FSC



Complementary power transistors

Features

■ Complementary NPN-PNP devices

Applications

■ Power linear and switching

Description

The device is manufactured in Planar technology with "Base Island" layout. The resulting transistor shows exceptional high gain performance coupled with very low saturation voltage. The PNP type is BD244C.

Josolete Product(s)

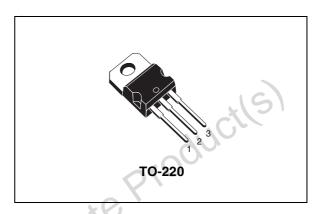


Figure 1. Internal schematic diagram

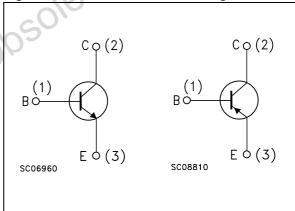


Table 1. Device summary

Order code	Marking	Package	Packaging
BD243C BD244C	BD243C BD244C	TO-220	Tube

Absolute maximum ratings 1

Table 2. **Absolute maximum ratings**

Collector-base voltage (I _E = 0) Collector-emitter voltage (I _B = 0) Emitte-base voltage (I _C = 0) Collector current Collector peak current (t _P < 5ms) Base current Total dissipation at T _C = 25°C Storage temperature Max. operating junction temperature types voltage and current values are negative	10 1 1 3 6 6 65 t	BD244C (PNP) 00 5 6 0 2 5 150	V V V A A A W • °C
Collector-emitter voltage (I _B = 0) Emitte-base voltage (I _C = 0) Collector current Collector peak current (t _P < 5ms) Base current Total dissipation at T _C = 25°C Storage temperature Max. operating junction temperature	10 1 1 3 6 6 65 t	00 5 6 0 2	V V A A A W
Emitte-base voltage (I _C = 0) Collector current Collector peak current (t _P < 5ms) Base current Total dissipation at T _C = 25°C Storage temperature Max. operating junction temperature	1 1 6 6 t	5 6 0 2	V A A A W
Collector current Collector peak current (t _P < 5ms) Base current Total dissipation at T _C = 25°C Storage temperature Max. operating junction temperature	1 1 5 6 6 6 6 6 6 6 6 6 6 6 6 6 6 6 6 6	6 0 2	A A A W
Collector peak current (t _P < 5ms) Base current Total dissipation at T _C = 25°C Storage temperature Max. operating junction temperature	1 6 -65 t	0	A A W
Base current Total dissipation at T _c = 25°C Storage temperature Max. operating junction temperature	65 t	2	A W
Total dissipation at T _c = 25°C Storage temperature Max. operating junction temperature	-65 to	55	W
Storage temperature Max. operating junction temperature	-65 t		
Max. operating junction temperature		o 150	°C
	_ X Ø 1:		i
types voltage and current values are negative		50	°C
Produci(s)			
	blognici(2).	Product(s).	Product(s).

2 **Electrical characteristics**

 $(T_{case} = 25^{\circ}C; unless otherwise specified)$

Table 3. **Electrical characteristics**

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 100V			0.4	mA
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 60V			0.7	mA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = 5V		(mA
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 30mA	100	90		V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 6A$ $I_B = 1A$			1.5	V
V _{BE} ⁽¹⁾	Base-emitter voltage	$I_C = 6A$ $I_B = 1A$			2	V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 0.3 \text{mA}$ $V_{CE} = 4 \text{V}$ $I_C = 3 \text{A}$ $V_{CE} = 4 \text{V}$	30 15			

^{1.} Pulsed duration = 300 ms, duty cycle \leq 2%.

Note:

Obsolete Product For PNP types voltage and current values are negative.

Electrical characteristics BD243C BD244C

2.1 Typical characteristics

Figure 2. Safe operating area

Figure 3. Derating curve

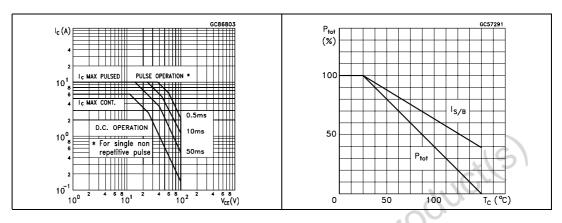


Figure 4. DC current gain (NPN)

Figure 5. DC current gain (PNP)

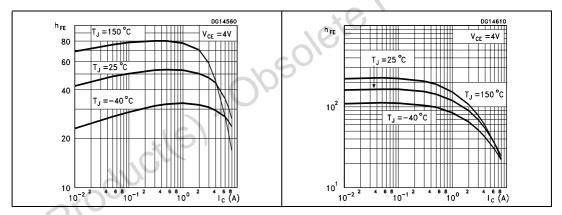


Figure 6. Collector-emitter saturation voltage (NPN)

Figure 7. Collector-emitter saturation voltage (PNP)

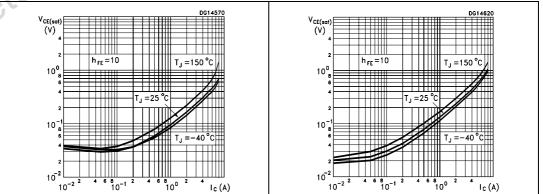


Figure 8. Base-emitter saturation voltage (NPN)

Figure 9. Base-emitter saturation voltage (PNP)

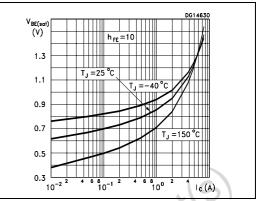


Figure 10. Base-emitter saturation voltage (NPN)

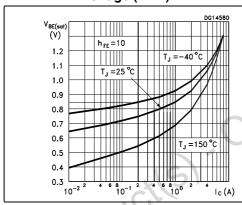


Figure 11. Base-emitter saturation voltage (PNP)

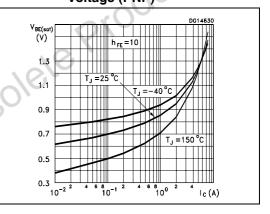
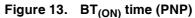
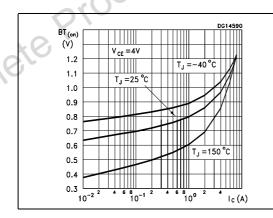
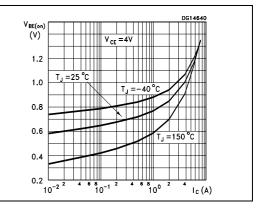


Figure 12. BT(ON) time (NPN)







Electrical characteristics BD243C BD244C

Figure 14. Resistive load switching time Figure 15. Resistive load switching time (NPN) (PNP)

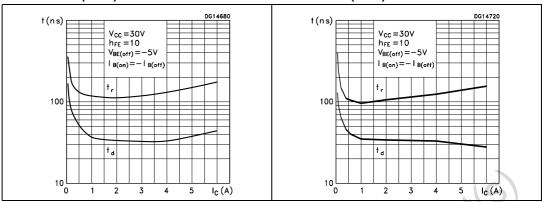


Figure 16. Resistive load switching time Figure 17. Resistive load switching time (NPN) (PNP)

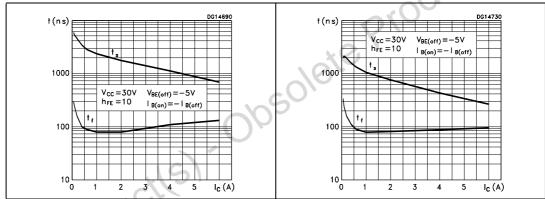
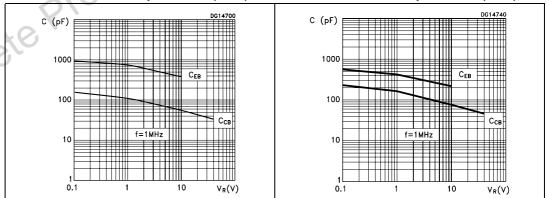


Figure 18. Collector-base and collector- Figure 19. Collector-base and collector- emitter capacitance (NPN) emitter capacitance (PNP)

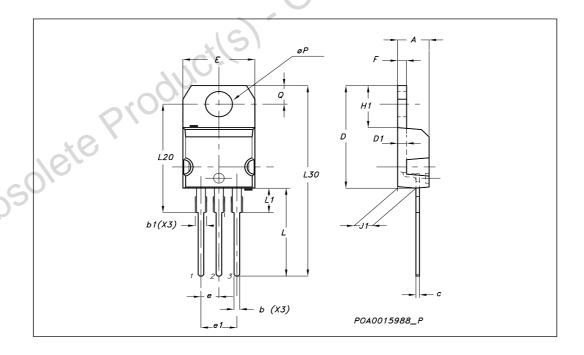


3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available Obsolete Product(s). at: www.st.com

TO-220 Mechanical data

DIM.		mm.				
DIM.	MIN.	TYP	MAX.			
Α	4.40		4.60			
b	0.61		0.88			
b1	1.14		1.70			
С	0.49		0.70			
D	15.25		15.75			
D1		1.27				
E	10		10.40			
е	2.40		2.70			
e1	4.95		5.15			
F	1.23		1.32			
H1	6.20		6.60			
J1	2.40		2.72			
L	13		14			
L1	3.50	*	3.93			
L20		16.40				
L30		28.90				
øΡ	3.75	1.50	3.85			
Q	2.65		2.95			



BD243C BD244C Revision history

4 Revision history

Table 4. Revision history

Date	Revision	Changes
13-Sep-2005	4	New datasheet according to MLD-PWR/05/1267
25-Jul-2007		Figures 2, 3, 4, 5, 6, 7, 8, 9, 10, 11, 12, 13, 14, 15, 16, 17, 18 and figure 19, added

Obsolete Product(s). Obsolete Product(s)

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577